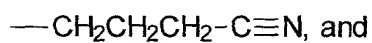
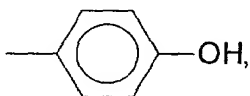
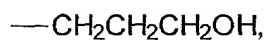


component selected from the group consisting of $C(CH_2OH)_3$, a sugar unit, and SiR_3 wherein R is a polar group selected from the group consisting of:

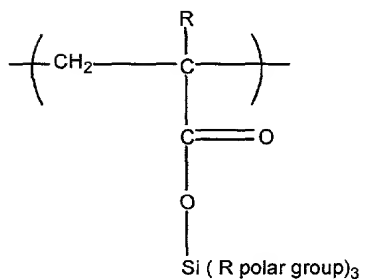
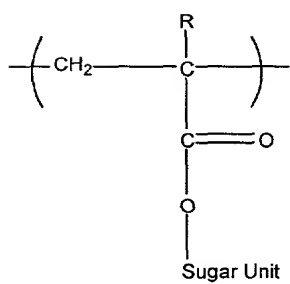
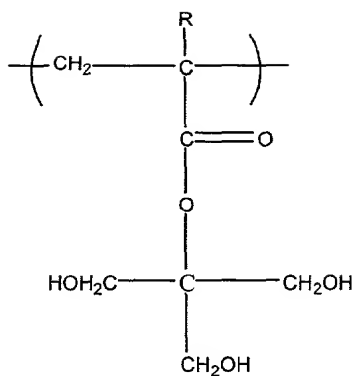


mixtures thereof.

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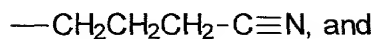
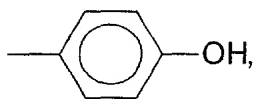
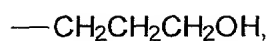
One specific embodiment of a polymer that may be used as a positive tone resist is a copolymer of fluoroacrylate having the following comonomer structures:

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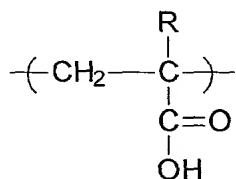
5

wherein R polar group is preferably selected from the group consisting of:



mixtures thereof.

- In one embodiment, upon exposure to radiation, the polar group is removed from the unit, thus resulting in the formation of a carboxylic acid unit that has a higher solubility in CO_2 as illustrated by the following:



- Not intending to be bound by theory, another embodiment that can allow for an increase of the polymer solubility upon exposure to radiation is to employ a polymer that is capable of undergoing chain scission upon such exposure, e.g., an alternating copolymer between a fluorinated alkyl allyl ether with sulfur dioxide. Upon exposure to radiation (e.g., e-beam), scission of the main polymer chain results and thus a lowering of the polymer molecular weight. Therefore, the resulting polymer has a higher solubility in CO_2 relative to the parent base resist of higher molecular weight.

An example an embodiment of a generic phase diagram for a positive resist is given in **FIG. 4**. Above each curve, the polymer (e.g., resin) is soluble